

3.27 (a) Determine the total number (#/cm<sup>3</sup>) of energy states in silicon between  $E_v$  and  $E_v - 3kT$  at (i)  $T = 300$  K and (ii)  $T = 400$  K.

$$a) \text{ Per (3.75), } g_v(E) = \frac{4\pi(2m_p^*)^{3/2}}{h^3} \sqrt{E_v - E}$$

$$N_v = \int_{E_v - 3k_B T}^{E_v} g_v(E) dE = \frac{4\pi(2m_p^*)^{3/2}}{h^3} \int_{E_v - 3k_B T}^{E_v} (E_v - E)^{1/2} dE$$

$$= \frac{4\pi(2m_p^*)^{3/2}}{h^3} \left(-\frac{2}{3}\right) (E_v - E)^{3/2} \Big|_{E_v - 3k_B T}^{E_v}$$

$$= \frac{4\pi(2m_p^*)^{3/2}}{h^3} \left(+\frac{2}{3}\right) [0 + 3k_B T]^{3/2}$$

From Table 4.1,  $m_p^* = 0.56 m_0$

$$N_v = \frac{4\pi [2(0.56)9.1093837 \times 10^{-31}]^{3/2}}{(6.62607015 \times 10^{-34})^3} \left(\frac{2}{3}\right) [3k_B T]^{3/2}$$

$$= 4.30607 \times 10^{21} T^{3/2}$$

(i)  $T = 300$  K

$$N_v = 4.30607 \times 10^{21} (300)^{3/2}$$

$$N_v = 4.11055 \times 10^{25} \#/\text{m}^3 = 4.1105 \times 10^{19} \#/\text{cm}^3$$


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(ii)  $T = 400$  K

$$N_v = 4.30607 \times 10^{21} (400)^{3/2}$$

$$N_v = 6.3286 \times 10^{25} \#/\text{m}^3 = 6.3286 \times 10^{19} \#/\text{cm}^3$$


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